

DESCRIPTION



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METHOD FOR MOUNTING SEMICONDUCTOR ELEMENT TO CIRCUIT BOARD,
AND SEMICONDUCTOR DEVICE

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TECHNICAL FIELD

The present invention relates to a method for mounting a semiconductor element to a circuit board, which is used for electrically connecting projecting electrodes, i.e., bumps on the semiconductor element to electrodes on the circuit board, and a semiconductor device having the semiconductor element mounted on the circuit board according to the method.

15 BACKGROUND ART

U.S.P. No. 4661192 discloses in the published specification a method for forming bumps on a semiconductor element by ball bonding and a method for bonding the semiconductor element. The conventional methods will be described.

In Fig. 25, a high voltage of several thousands volts is impressed from a discharge electrode (torch) 17 to a leading end 16a of an Au wire 16 extending from a leading end of a capillary 15. While a discharge current flows between the torch 17 and the leading end 16a of the wire,



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the wire 16 is turned to a high temperature from the leading end 16a and then melted, resulting in a gold ball 18 as shown in Fig. 26. The ball 18 is fixed onto an electrode 3a of a semiconductor element 3 by the capillary 15, thereby forming a bump bottom part 19, as in Fig. 27. Thereafter, the capillary 15 is pulled upward as in Fig. 28. The capillary 15 is looped above the bump bottom part 19, so that the wire 16 is tightly adhered to the bump bottom part 19, and then the wire is cut. A bump 20 is formed in this manner.

A semiconductor element 3 having the bumps 20 formed as above is pressed to a stage 14 having a flat face as in Fig. 29. In consequence, leading end parts of the bumps 20 are turned flat. Then, as indicated in Fig. 30, the semiconductor element 3 with the flattened bumps 20 is brought in touch with a conductive adhesive 6 applied on a stage 5 to transfer the conductive adhesive 6 to the flattened bumps 20. In Fig. 31, the semiconductor element 3 having the bumps 20 with the conductive adhesive 6 transferred thereon is registered to electrodes 2 on a circuit board 1 and fixed, whereby the semiconductor element is electrically connected to the circuit board 1.

As described hereinabove, conventionally, the semiconductor element 3 and circuit board 1 are bonded only by the conductive adhesive 6 transferred to the bumps 20 of

the semiconductor element 3. As such, the bonding between the semiconductor element 3 and circuit board 1 has merely a bonding strength of an area at the leading ends of the bumps 20 of the semiconductor element 3, and the conductive adhesive 6 exerts a strength as low as 1-2.0g at every bonded part because only a small amount of the conductive adhesive 6 is used so as to lower a volume resistivity. Such inconveniences are consequently brought about that the bonded part cracks because of a warp of the circuit board 1 or a stress when the conductive adhesive 6 is set, a connection resistance value is increased, and a disconnection at the bonded part is arised.

~~DISCLOSURE OF INVENTION~~

An object of the present invention is therefore to provide a method for mounting a semiconductor element to a circuit board whereby connection reliability and connection strength are enhanced in bonding between the semiconductor element and circuit board, and a connection resistance value is stabilized low, and a semiconductor device having a semiconductor element mounted to a circuit board by the method.

In order to accomplish the above-described object, according to a first aspect of the present invention, a method for mounting a semiconductor element to a circuit board, which comprises:

- 3a -

US-Patent 5,210,938 discloses a method of assembling an electronic part device in a circuit board wherein an electrode formed on the electronic part device and a conductive pattern formed on this circuit board so as to be opposite to the electrode or positioned. A thermosetting resin sheet including a thermally shrinkable particle and provided between the electronic part device and the circuit board is hardened and shrunk. If the thickness of the sheet is smaller than the size of the gap between the electronic part device and the circuit board, the semiconductor device on the circuit board does not adhere perfectly to each other and then are easy to come off each other.

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25 board, which comprises:

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applying in a liquid state
~~disposing~~ an insulating adhesive having a property of
shrinking upon being set, at least at either of opposite
faces confronted to each other of the circuit board and
semiconductor element;

5 registering the circuit board and semiconductor
element so that an electrode on the circuit board
corresponds to a projecting electrode on the semiconductor
element;

coupling the opposite faces of the circuit board and
10 semiconductor element by the insulating adhesive; and

setting the insulating adhesive, so that the electrode
on the circuit board and the projecting electrode on the
semiconductor element are electrically connected through
the shrinkage of the insulating adhesive so as ^{fix} to the
15 semiconductor element and circuit board ~~are fixed~~ in a
coupled state.

A semiconductor device according to a second
aspect of the present invention has a semiconductor element
mounted to a circuit board according to the above mount
20 method of the first aspect.

According to the mount method for a semiconductor
element to a circuit board of the first aspect and the
semiconductor device of the second aspect, the
semiconductor element and circuit board are connected with
25 the use of the insulating adhesive, and therefore connected

rigidly in comparison with the conventional art whereby the connection is achieved only by the projecting electrode of the semiconductor element and the electrode of the circuit board. Therefore, a connection resistance value at the projecting electrode of the semiconductor element and the electrode of the circuit board is reduced and less varied, and at the same time, connection strength is high, thereby realizing highly reliable bonding.

10 BRIEF DESCRIPTION OF DRAWINGS

These and other aspects and features of the present invention will become clear from the following description taken in conjunction with the preferred embodiments thereof with reference to the accompanying drawings in which:

Fig. 1 is a sectional view showing the structure of a semiconductor device in an embodiment of the present invention;

Fig. 2 is a diagram of one step of a manufacture process of the semiconductor device of Fig. 1, particularly in a state where a conductive adhesive is transferred to projecting electrodes of a semiconductor element;

Fig. 3 is a diagram of one step of the manufacture process of the semiconductor device of Fig. 1, particularly in a state where an insulating adhesive is

transferred onto a circuit board;

Fig. 4 is a sectional view of a modified example of the semiconductor device of Fig. 1;

Fig. 5 is a sectional view of a further modified example of the semiconductor device of Fig. 1;

Fig. 6 is a sectional view of a yet modified example of the semiconductor device of Fig. 1;

Fig. 7 is a diagram of a state where a part of the semiconductor element is removed in the semiconductor device of Fig. 1;

Fig. 8 is a diagram of one step of the manufacture process in a modified example of the semiconductor device of Fig. 1;

Fig. 9 is a diagram of one step of the manufacture process of the modified example of the semiconductor device of Fig. 1, specifically, a succeeding step to Fig. 8;

Fig. 10 is a diagram of one step of the manufacture process of the modified example of the semiconductor device of Fig. 1, specifically, a succeeding step to Fig. 9;

Fig. 11 is a diagram of one step of the manufacture process of the modified example of the semiconductor device of Fig. 1, specifically, a succeeding step to Fig. 10;

Fig. 12 is a diagram of one step of the manufacture process of the modified example of the semiconductor device of Fig. 1, specifically, a succeeding step to Fig. 11;

5 Fig. 13 is a sectional view of the modified example of the semiconductor device of Fig. 1;

Fig. 14 is a diagram of a state where a sealing resin is injected to the semiconductor device of Fig. 1;

10 Fig. 15 is a diagram showing the constitution of an apparatus for injecting the sealing resin to the semiconductor device of Fig. 1;

Fig. 16 is a diagram of a state where the sealing resin is being injected to the semiconductor device of Fig. 1;

15 Fig. 17 is a sectional view of the semiconductor device of Fig. 1 with the sealing resin injected while coated with a heat-radiating resin;

Fig. 18 is a sectional view of the semiconductor device of Fig. 1 in a state where a second sealing resin is injected thereto;

20 Fig. 19 is a sectional view of the semiconductor device of Fig. 1 in a state where the second sealing resin is injected thereto;

25 Fig. 20 is a flow chart of an operation of a method for mounting a semiconductor element to a circuit

board according to an embodiment of the present invention;

Fig. 21 is a plan view of an arrangement of a rectangular insulating adhesive when the sealing resin is injected to the semiconductor device of Fig. 1 in one direction;

Fig. 22 is a plan view of an arrangement of an elliptical insulating adhesive when the sealing resin is injected to the semiconductor device of Fig. 1 in one direction;

Fig. 23 is a sectional view of the semiconductor device of the embodiment in another structure without using a conductive adhesive;

Fig. 24 is a sectional view of the semiconductor device of the embodiment in a different structure with using a spherical semiconductor element;

Fig. 25 is a diagram of one step of a process for forming a projecting electrode on an electrode of a semiconductor element, specifically indicating a leading end part of a capillary;

Fig. 26 is a diagram of one step of the process for forming the projecting electrode on the electrode of the semiconductor element, specifically showing a state with a ball formed at the leading end of the capillary;

Fig. 27 is a diagram of one step of the process for forming the projecting electrode on the electrode of

the semiconductor element, specifically showing a state with the ball of Fig. 26 pressed to the electrode on the semiconductor element;

Fig. 28 is a diagram of one step of the process for forming the projecting electrode on the electrode of the semiconductor element, specifically showing a state with the projecting electrode formed on the electrode on the semiconductor element;

Fig. 29 is a diagram of one step of the process for forming the projecting electrode on the electrode of the semiconductor element, specifically showing a state where projecting electrodes are uniformed in height;

Fig. 30 is a diagram of one step of the process for forming the projecting electrode on the electrode of the semiconductor element, specifically showing a state where a conductive adhesive is transferred to the projecting electrodes;

Fig. 31 is a diagram of a conventional semiconductor device.

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BEST MODE FOR CARRYING OUT THE INVENTION

A method for mounting a semiconductor element to a circuit board according to a preferred embodiment of the present invention, and a semiconductor device having a semiconductor element mounted to a circuit board by the

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method will be described with reference to the drawings throughout which like parts are designated by like reference numerals.

Fig. 1 shows a semiconductor device 100 in which
5 a semiconductor element 103 is mounted to a circuit board 101 according to a mount method in the preferred embodiment. The mount method for obtaining the semiconductor device 100 will be discussed hereinbelow.

Similar to the conventional semiconductor element
10 described with reference to Figs. 25-29, a projecting electrode 104 as a bump is formed to an electrode 103a of the semiconductor element 103. The projecting electrodes 104 are pressed to a flat face of a stage, so that leading end parts of the projecting electrodes are turned flat and
15 at the same time, uniformed in height from a surface of the semiconductor element 103. The projecting electrodes 104 are preferably formed of Au, Ni, Al, Cu or solder by plating or conventional ball bonding with the use of a wire described earlier. The formation method is not limited to
20 the above.

As indicated in Fig. 2 and a step 1 in Fig. 20 (the step is denoted by "S" in the drawing), each leading end part of the projecting electrodes 104 of the semiconductor element 103 is brought in touch with a
25 conductive adhesive 106 applied on the flat face of the

stage, whereby the conductive adhesive 106 is transferred to the leading end parts. The conductive adhesive 106 is any kind of filler having conductive properties, e.g., silver, gold or the like and not limited in material.

5 On the other hand, as shown in Fig. 3 and a step 2 in Fig. 20, in forming the semiconductor device 100 according to the present embodiment, a thermosetting insulating adhesive 107 is applied on an opposite face 101a confronting to the semiconductor element 103 at a position
10 not in touch with electrodes 102 which are to be connected to the projecting electrodes 104. Concretely, the insulating adhesive 107 is anything such as an epoxy-series resin, a silicone-series resin, a polyimide-series resin, etc. so long as it shrinks and sets by heat. As will be
15 described later, the insulating adhesive 107 is heated in a range of 60-200°C, preferably at 120°C in the case of the epoxy-series resin for 15 minutes to 2 hours, preferably for one hour so as to set and shrink in the same process as the conductive adhesive 106 of the projecting electrodes
20 104. Moreover, because of the need for the insulating adhesive 107 on the circuit board 101 to adhere to an opposite face 103b of the semiconductor element 103 thereby coupling the opposite faces 101a and 103b when the semiconductor element 103 is arranged on the circuit board
25 101, the insulating adhesive 107 should be formed like a

projection on the circuit board 101 as illustrated in Fig. 3 if the insulating adhesive 107 is in liquid state. For this reason, the insulating adhesive 107 has, when it is in liquid state, a viscosity of 4-300Pas, preferably 30Pas.

5 In the description of the embodiment, the semiconductor element 103 to which the insulating adhesive 107 is applied or adhered is exemplified in the form of one chip, but not restricted to this form and may be a wafer before cut to one chip.

10 An example of physical properties of the insulating adhesive 107 formed of epoxy-series resin is indicated hereinbelow. The insulating adhesive 107 is set by heating at 120°C for 30 minutes. A thermal expansion coefficient is $29 \times 10^{-6}/^{\circ}\text{C}$, a Young's modulus is 10.5GPa, a
15 glass transition point is 113°C, a bonding strength is 88.26N and a setting stress is $882.6 \times 10^6 \text{Pa}$.

20 The setting stress applied to the semiconductor element 103 when the insulating adhesive 107 is set and shrunken has the risk of damage to the semiconductor element 103. While the setting stress changes in accordance with a thickness and a size of the semiconductor element 103, a material and a breadth of a wiring, and a thickness, a size and a material of the circuit board 101, when the semiconductor element is formed of 0.4mm-thick
25 silicon with 10mm square and the circuit board is formed of

0.8mm-thick glass epoxy resin, the setting stress within 392.3×10^6 – 1176.8×10^6 Pa never damages the semiconductor element. In other words, if the insulating adhesive 107 used acts the setting stress as above to the semiconductor element 103 and circuit board 101 when set and shrunken, the damage to the semiconductor element 103 and circuit board 101 can be avoided.

In step 3 of Fig. 20, the projecting electrodes 104 of the semiconductor element 103 are registered on the electrodes 102 of the circuit board 101 and subsequently disposed to the electrodes 102 on the circuit board 101 by the conductive adhesive 106. Consequent to the registering, the interposed insulating adhesive 107 couples the opposite face 101a of the circuit board 101 with the opposite face 103b of the semiconductor element 103 between the semiconductor element 103 and circuit board 101.

Then in step 4 called by a parallel setting process of Fig. 20, the semiconductor element 103 and circuit board 101, i.e., the conductive adhesive 106 and insulating adhesive 107 are set in the same process by a cure oven heating and setting the insulating adhesive 107 and conductive adhesive 106, or by a heating tool with a heater heating at least one of the semiconductor element 103 and circuit board 101. As a result, the semiconductor device 100 shown in Fig. 1 is obtained. At this time, the

circuit board 101 and semiconductor element 103 are not temporarily fixed, but eternally set by the setting of the conductive adhesive 106 and insulating adhesive 107.

A heating temperature in the cure oven is
5 120±10°C in the embodiment in the case of the epoxy-series resin adhesive. The conductive adhesive 106 and insulating adhesive 107 are set under the same condition.

In the step 4, the insulating adhesive 107 is adapted to be set and shrunken earlier than the conductive
10 adhesive 106. The reason for adapting such the timing is that if the conductive adhesive 106 were set earlier in a state without the projecting electrodes 104 and the electrodes 102 on the circuit board 101 bonded, the defective bonded state is unrepairable after the setting
15 and shrink of the insulating adhesive 107. The setting is executed with a timing, for instance, that the insulating adhesive 107 is set and shrunken in 25 minutes and the conductive adhesive 106 is set in 40 minutes at the setting temperature of 100°C, the insulating adhesive 107 is set
20 and shrunken in 20 minutes and the conductive adhesive 106 is set in 35 minutes at the setting temperature of 120°C, or the insulating adhesive 107 is set and shrunken in 10 minutes and the conductive adhesive 106 is set in 20 minutes at the setting temperature of 150°C.

25 In order to set and shrink the insulating

adhesive 107 earlier than the conductive adhesive 106 with the above-described timing and also to surely bond the projecting electrodes 104 with the electrodes 102 on the circuit board 101 by the insulating adhesive 107 set and
5 shrunken earlier without causing damage, e.g., cracks or the like to the semiconductor element 103, the insulating adhesive 107 that has the above-described physical properties is employed. Moreover, in order to secure a timing shift of the setting, the insulating adhesive 107 is
10 adapted to have a gelling time and a setting time which are earlier than those of the conductive adhesive 106. Further, the insulating adhesive 107 is adapted to be set at a lower temperature so as not to damage the semiconductor element 103 by the setting and shrink thereof. A difference of the
15 gelling time and the setting time between the insulating adhesive 107 and conductive adhesive 106 is due to a difference of components. That is, the insulating adhesive 107 is set as an adhesive component contained in the insulating adhesive 107 is set, while, the conductive
20 adhesive 106 is dried and solidified when a solvent component called as BCA (butyl Carbitol acetate) contained in the conductive adhesive 106 evaporates. The presence/absence of the solvent component is one reason for the difference of the gelling time and setting time.

25 The setting stress applied to the semiconductor

element 103 and circuit board 101, i.e., internal stress changes corresponding to a setting temperature, for example, $490.3 \times 10^6 \text{ Pa}$ at 100°C for 30 minutes, $882.6 \times 10^6 \text{ Pa}$ at 120°C for 30 minutes and $1520.0 \times 10^6 \text{ Pa}$ at 150°C for 15 minutes. Therefore, not only the timing shift of the setting is required, but the setting stress should be $392.3 \times 10^6 - 1176.8 \times 10^6 \text{ Pa}$ as mentioned earlier.

Since the semiconductor element 103 and circuit board 101 are connected by the insulating adhesive 107 as well as by the conductive adhesive 106, connection strength between the circuit board 101 and semiconductor element 103 is increased owing to the setting and shrink of the insulating adhesive 107 as compared with the conventional art in spite of the stress impressed to the connected part between the projecting electrodes 104 and electrodes 102 of the circuit board 101 due to a difference of thermal expansion coefficients of the circuit board 101 and semiconductor element 103 and a warp of the circuit board 101. Accordingly, a connection resistance between the projecting electrodes 104 and electrodes 102 of the circuit board 101 is decreased and less varied, and at the same time, the semiconductor element 103 and circuit board 101 are bonded stably and highly reliably with large connection strength.

Although the insulating adhesive 107 is applied

onto the circuit board 101 in order to simplify the manufacture process in the foregoing description, the insulating adhesive 107 may be applied to the opposite face 103b of the semiconductor element 103, or both opposite
5 faces 101a and 103b of the circuit board 101 and semiconductor element 103.

In addition, although the insulating adhesive 107 is applied only at one point between the semiconductor element 103 and circuit board 101 as indicated in Fig. 1,
10 the present invention is not limited to this and the insulating adhesive 107 can be applied at a plurality of points as in semiconductor devices 115, 116 shown in Figs. 5, 6 in accordance with an increase of an area of the semiconductor element 103. When the insulating adhesive
15 107 is applied at two or more points, the amount of the insulating adhesive 107 applied once is reduced, so that variations in application amount is decreased, enabling a constant amount of the insulating adhesive 107 to be applied. The insulating adhesive 107 is prevented from
20 spreading to the electrodes 102 of the circuit board 101 when the semiconductor element 103 is mounted on the circuit board 101.

When the semiconductor element 103 and circuit board 101 are connected with each other as in Figs. 1, 5
25 and 6, if the insulating adhesive 107 is disposed so as not

to adhere any of the electrodes 103a of the semiconductor element 103 and electrodes 102 of the circuit board 101, the following effects are exerted. In the event the semiconductor element 103 is detected to be defective after
5 being mounted to the circuit board, the insulating adhesive 107 of epoxy-series resin not adhering to at least one of the electrodes 102 on the circuit board 101 can be softened by heating the defective semiconductor element to about 200-230°C which is a temperature not lower than the glass
10 transition point of the insulating adhesive, to be reduced in bond strength. The insulating adhesive 107 can hence be separated from the circuit board 101, and the semiconductor element 103 is removed in about 15 seconds from the circuit board 101. So, the circuit board 101 can be used again, to
15 which a good semiconductor element 103 is mounted.

Although the aforementioned effect is lost, the insulating adhesive 107 may be disposed to adhere to the electrode 102 of the circuit board 101 as in a semiconductor device 110 of Fig. 4, or both the electrode
20 103a of the semiconductor element 103 and the electrode 102 of the circuit board 101.

The insulating adhesive 107 in the foregoing description is in liquid state. However, the insulating adhesive may be molded to a pellet or film, whereby the
25 amount of the insulating adhesive 107 supplied varies less.

The insulating adhesive 107 of a constant amount can be supplied.

At this time, the insulating adhesive 107 shaped in the pellet or film is preferably rectangular or elliptical in plane having a length-to-breadth ratio of not smaller than 1. As will be described later, a first sealing resin 161 is injected to a gap between the semiconductor element 103 and circuit board 101 as shown in Fig. 14 after the semiconductor element 103 and circuit board 101 are fixed by the insulating adhesive 107. When the first sealing resin 161 is injected into the gap from a side end face and a neighboring part 206 of the semiconductor element 103 in one direction as represented by arrows 201 in Figs. 21 and 22, air bubbles are formed at a rear end part 202 of the insulating adhesive 107 in the injection direction of the arrow 201, resulting in the formation of a void part. For eliminating the air bubbles, therefore, the insulating adhesive 107 is arranged to be streamlined to the injection direction, and further the insulating adhesive 107 is arranged in plane so that a ratio of a lateral size 204 thereof in the injection direction of the arrow 201 to a longitudinal size 203 thereof in a direction orthogonal to the injection direction is not smaller than 1.

The above condition of the length-and-breadth

ratio of not smaller than 1 can be applied also to a plane shape of the applied insulating adhesive 107 when the insulating adhesive 107 is in liquid state. Since it is necessary for the pellet or film-shaped insulating adhesive 107 on the circuit board 101 to touch the opposite face 103b of the semiconductor element 103 when the semiconductor element 103 is mounted on the circuit board 101, a height of the pellet or film-shaped insulating adhesive 107 from the opposite face 101a of the circuit board 101 is such that allows the touch. For example, the pellet or film in plane is smaller than a distance between the electrodes 103a of the semiconductor element 103 shown in Fig. 1 and has the height corresponding to a distance between the semiconductor element 103 and circuit board 101, i.e., 20-200 μ m, and slightly exceeds the distance.

In the case where the pellet or film-shaped insulating adhesive 107 is employed, the following effects are obtained. As described earlier, when the insulating adhesive 107 in liquid state is used, an application operation for the insulating adhesive 107 and a mount operation for the semiconductor element 103 onto the circuit board 101 are carried out separately as in steps 2 and 3 in Fig. 20. To the contrary, when the pellet or film-shaped insulating adhesive 107 is used, since the adhesive is solid, the pellet or film-shaped insulating

adhesive 107 can be disposed between the circuit board 101 and semiconductor element 103 while the aforementioned mount operation is being performed.

Although the insulating adhesive 107 is directly
5 adhered to the opposite face 103b of the semiconductor element 103 in the above description, as will be depicted later, an insulating resin 153 of, e.g., epoxy-series resin may be formed at the opposite face 103b of the semiconductor element 103 beforehand, thereby constituting
10 a semiconductor element 150, and thereafter the semiconductor element 150 is connected with the circuit board 101 by the insulating adhesive 107. More specifically, referring to Fig. 8, after the projecting electrodes 104 are formed on the electrodes 103a of the
15 semiconductor element 103, the semiconductor element 103 is fitted on a rotary table 151. The insulating resin 153 is applied to a nearly central part on the opposite face 103b of the semiconductor element 103, and the rotary table 151 is rotated in an arrow direction. In consequence, as in
20 Fig. 9, the insulating resin 153 is scattered by a centrifugal force, so that the opposite face 103b of the semiconductor element 103 and the electrodes 103a in the periphery of the projecting electrodes 104 are covered with the insulating resin 153. But a leading end parts of the
25 projecting electrodes 104 are exposed from the insulating

resin 153. The insulating resin 153 is then set. After the setting, the leading end parts of the projecting electrodes 104 are pressed to a base material 152 having a flat face, as shown in Figs. 10 and 11, thereby making the leading end parts of the projecting electrodes 104 flat and exposed as a bond face. Afterwards, as in Figs. 12 and 13, the conductive adhesive 106 is provided at the leading end parts of the projecting electrodes 104 as described earlier, and the insulating adhesive 107 is disposed between the semiconductor element 150 and circuit board 101, whereby the semiconductor element 150 is connected to the circuit board 101. The semiconductor device thus manufactured becomes a semiconductor device 155 shown in Fig. 13.

As described hereinabove, when the insulating resin 153 is formed on the opposite face 103b of the semiconductor element 103, the insulating resin 153 protects the semiconductor element 103 and also the electrodes 103a in the periphery of the projecting electrodes 104, and at the same time, makes the semiconductor element superiorly resistive to moisture after mounted on the circuit board 101 and prevents the electrodes 103a of the semiconductor element 103 from being corroded. According to the semiconductor device 155, a process of injecting and setting the insulating resin to a gap between the circuit board 101 and semiconductor element

103 is effectively eliminated.

While the insulating resin 153 may not contain a material such as silica or the like controlling the thermal expansion of the insulating resin 153, if the insulating resin contains the material, it becomes almost equal to the insulating adhesive 107 in component, thereby reducing a stress at an interface between the insulating resin 153 and insulating adhesive 107.

In each of the above-described semiconductor devices 100, 110, 115, 116, 155, the first sealing resin 161 is injected to the gap between the semiconductor element and circuit board, e.g., in a manner as illustrated in Fig. 14 or in step 5 of Fig. 20. The injection of the first sealing resin 161 may be omitted in the semiconductor device 155 as discussed above. An injection operation of the first sealing resin 161 will be described now by way of example of the semiconductor device 100.

In a way of the injection method, the first sealing resin 161 is injected by a resin injection device 171 from the side end face of the semiconductor device 100 and one of parts in the vicinity of the side end face, as indicated by the reference numeral 206 in Fig. 14.

Preferably, the interior of a working chamber 173 is reduced in a pressure lowered than an atmospheric pressure by an air discharge device 172 after the

semiconductor device 100 is set in the chamber 173 the interior of which can be reduced in the pressure lowered than the atmospheric pressure by the air discharge device 172. Under the pressure-reduced state, the first sealing resin 161 is applied onto the circuit board 101 along four sides of the semiconductor device 100 from the side end face and the neighboring part 206 of the semiconductor device 100 by a resin feed device 174 as represented by arrows. After the application is completed, the interior of the chamber 173 is returned to the atmospheric pressure. Meanwhile, the gap part between the semiconductor element 103 and circuit board 101 sealed by the first sealing resin 161 applied along the four sides of the semiconductor device 100 is still in the pressure-reduced state. Because of a pressure difference, the first sealing resin 161 applied along the four sides invades the gap as shown in Fig. 16 thereby filling the gap. The amount of the first sealing resin 161 applied at this time is such as seals the gap between the semiconductor element 103 and circuit board 101, thereby preventing invasion of moisture and corrosion, easing a thermal stress and securing reliability at the bonded part.

According to the above-described injection method, in comparison with the method of applying the insulating sealing resin from the side end part of the semiconductor

element 103 and the neighboring part 206 in the atmospheric pressure, the sealing resin can be injected to the gap in a shorter time. Moreover, even if the semiconductor element 103 is as large as 15x15mm or more, the sealing resin can
5 be injected easily in a short time.

A heat-radiating resin 163 may be provided to the semiconductor device having the first sealing resin 161 filled in the gap as above, in a manner as shown in Fig. 17 to cover the whole face of the semiconductor device. In
10 this case, the heat-radiating resin 163 has a thermal conductivity in a range of 0.2-2W/mk, more preferably, 1W/mk or larger to effectively radiate the heat generated at the semiconductor device. If alumina or the like metallic filler of good thermal conductivity is included in
15 the first sealing resin 161, heat radiation efficiency of the semiconductor element 103 can be improved even without the heat-radiating resin 163. When the metallic filler is used, the filler is coated with a resin coat so as to negate conductivity of the filler.

20 In place of the method of injecting the sealing resin, the semiconductor element 103 can be sealed by covering the semiconductor device 100, for instance, with a second sealing resin 162 as shown in Figs. 18 and 19. The second sealing resin 162 is, e.g., a film-shape or in
25 liquid state. Fig. 18 shows the liquid state resin, while

Fig. 19 shows the film of the resin. Concretely, after the semiconductor device 100 is heated in the chamber 173 in the pressure-reduced state, the whole face of the semiconductor element 103 is covered with the second sealing resin 162. The working chamber 173 is returned to the atmospheric pressure, and the second sealing resin 162 is set, whereby the semiconductor device 100 is sealed.

Accordingly, as compared with the method of applying and injecting the insulating sealing resin from the side end face and the neighboring part 206 of the semiconductor element 103 in the atmospheric pressure, the second sealing resin can be applied in a short time in the form of a sheet, which can cope with a size increase of the semiconductor element 103.

Similar to the case when the first sealing resin 161 is used, the heat-radiating resin 163 may be additionally provided, or the alumina filler or the like may be included in the second sealing resin 162.

The first sealing resin 161 and second sealing resin 162 are preferably of epoxy or acrylic-series, more preferably composed of a material containing an epoxy component. The first sealing resin 161 and second sealing resin 162 may be thermoplastic resin, not restricted to thermoset resin.

In the above semiconductor devices 100, 110, 115,

116, 155, the projecting electrodes 104 are connected to the electrodes 102 on the circuit board 101 via the conductive adhesive 106. However, the conductive adhesive 106 is not necessarily required. Fig. 23 represents a semiconductor device 211 wherein the semiconductor element 103 and circuit board 101 are fixed with each other only by the insulating adhesive 107, without using the conductive adhesive 106. Since the insulating adhesive 107 has shrink properties, the semiconductor element 103 and circuit board 101 are pulled one another when connected via the insulating adhesive 107, and consequently the projecting electrodes 104 are butted and electrically connected to the electrodes 102 on the circuit board 101.

Even when the semiconductor element 103 and circuit board 101 are fixed only by the insulating adhesive 107 as above, the projecting electrodes 104 are surely connected to the electrodes 102 on the circuit board 101 via the insulating adhesive 107. However, it is better to use the conductive adhesive 106 together to enhance connection reliability more as described earlier.

Although the semiconductor element 103 is flat in the foregoing example, the mount method is not limited to the example and is applicable to a spherical semiconductor element 213 as shown in Fig. 24. A semiconductor device 215 is obtained with the spherical semiconductor element

mounted to the circuit board with the use of the mount method of the above embodiment.

Although the present invention has been fully described in connection with the preferred embodiment thereof with reference to the accompanying drawings, it is to be noted that various changes and modifications are apparent to those skilled in the art. Such changes and modifications are to be understood as included within the scope of the present invention as defined by the appended claims unless they depart therefrom.

New claims 1 to 24

1. A method for mounting a semiconductor element (103) to a circuit board (101), which comprises:
applying an insulating adhesive (107) in a liquid state having a property of shrinking upon being set, at least at either of opposite faces (101a, 103b) confronted to each other of the circuit board (101) and semiconductor element (103);
registering the circuit board (101) and semiconductor element (103) so that an electrode (102) on the circuit board corresponds to a projecting electrode (104) on the semiconductor element (103);
coupling the opposite faces (101a, 103b) of the circuit board and semiconductor element (103) by the insulating adhesive (107); and
setting the insulating adhesive (107) so that the electrode (102) on the circuit board (101) and the projecting electrode (104) on the semiconductor element (103) are electrically connected through the shrinkage of the insulating adhesive (107) so as to fix the semiconductor element (103) and circuit board (101) in a coupled state.
2. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 1,
wherein the insulating adhesive (107) is applied at a position not to be in touch with any of the electrode (102) on the circuit board (101) and the projecting electrode (104) on the semiconductor element (103) in the coupled state of the semiconductor element (103) and circuit board (101).

3. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 1 or 2,
wherein the insulating adhesive (107) is applied at a plurality of points on the either of opposite faces (101a, 103b) so as to reduce an application amount of the insulating adhesive (107) applied once, so that variations in the application amount is decreased.
4. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 3,
wherein the insulating adhesive (107) is set by a cure oven.
5. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 4,
which comprises, after fixing the circuit board (101) and semiconductor element (103), injecting a first sealing resin agent (161) to a gap between the circuit board (101) and semiconductor element (103) from a side end face and its neighboring part (206) of the semiconductor element (103) on the circuit board (101).
6. A method for mounting a semiconductor element (103) to a circuit board (101), which comprises:
disposing an insulating adhesive (107) having a property of shrinking upon being set, at least at either of opposite faces (101a, 103b) confronted to each other of the circuit board (101) and semiconductor element (103);
registering the circuit board (101) and semiconductor element (103) so that an electrode (102) on the circuit board (101) corresponds to a projecting electrode (104) on the semiconductor element (103);
coupling the opposite faces (101a, 103b) of the circuit board (101) and semiconductor element (103) by the insulating adhesive (107); and
setting the insulating adhesive (107), so that the electrode (102) on the circuit board (101) and the projecting electrode (104) on the semiconductor element (103) are electrically connected through the shrinkage of the insulating adhesive (107) so as to fix the semiconductor element (103) and circuit board (101) in a coupled state,
the method further comprising
applying, before disposing the insulating adhesive (107), an insulating resin (153) for protecting an electrode (103a) on the semiconductor element (103) to the opposite face (103b) of the semiconductor element (103)

except for a part of the projecting electrode (104) connected to the electrode (102) on the circuit board (101), wherein after the insulating resin (153) sets, the insulating adhesive (107) is disposed at least at either of opposite faces (101a, 103b).

7. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 6, wherein the insulating resin (153) is applied by dropping the insulating resin (153) to a nearly central part on the opposite face (103b) of the semiconductor element (103) fixed on a rotary table (151) and rotating the rotary table (151).
8. The method for mounting a semiconductor element (103) to a circuit board (101) according to claims 6 or 7, which comprises, after fixing the circuit board (101) and semiconductor element (103), injecting a first sealing resin agent (161) to a gap between the circuit board (101) and semiconductor element (103) from a side end face and its neighboring part (206) of the semiconductor element (103) on the circuit board (101).
9. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 8, wherein, the insulating adhesive (107) is a pellet-shaped or film-shaped and the first sealing resin agent (161) is injected in one direction into the gap between the circuit board (101) and semiconductor element (103) from the side end face and its neighboring part (206) of the semiconductor element (103) on the circuit board (101), the insulating adhesive (107) disposed is rectangular or elliptical in plane with a size ratio of a lengthwise direction orthogonal to an injection direction of the one direction of the first sealing resin agent (161) to a breadthwise direction in parallel to the injection direction of not smaller than 1.
10. The method for mounting a semiconductor element (103) to a circuit board (101) according to claims 5 or 8, wherein the injection of the first sealing resin agent (161) to the gap between the circuit board (101) and semiconductor element (103) comprises:
bringing the circuit board (101) and semiconductor element (103) under a

pressure-reduced state lower than an atmospheric pressure after fixing the same;

applying the first sealing resin agent (161) in a whole periphery of the semiconductor element (103) along the side end face and its neighboring part (206) of the semiconductor element (103) under the pressure-reduced state so as to seal the gap; and

returning the circuit board (101) and semiconductor element (103) to the atmospheric pressure, so that the first sealing resin agent (161) applied to the side end face and its neighboring part (206) invades the gap consequent to a pressure difference.

11. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 5 and 8 to 10, further comprising: covering the semiconductor element (103) with a heat-radiating resin (163) after the first sealing resin agent (161) is injected.
12. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 4, 6 and 7, further including: after fixing the circuit board (101) and semiconductor element (103), bringing the circuit board (101) and semiconductor element (103) under a pressure-reduced state lower than an atmospheric pressure; covering the semiconductor element (103) with a second sealing resin agent (162) under the pressure-reduced state; and returning the circuit board (101) and semiconductor element (103) to the atmospheric pressure so as to seal the semiconductor element (103) onto the circuit board (101) by the second sealing resin agent (162).
13. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 12, wherein the second sealing resin agent (162) is a resin having a property of softening by heat, which is heated, returned to the atmospheric pressure and set when the semiconductor element (103) is covered with the second sealing resin agent (162) under the pressure-reduced state.
14. The method for mounting a semiconductor element (103) to a circuit board (101) according to claims 12 or 13, further including: coating the second sealing resin agent (162) with a heat-radiating resin (163) after the semiconductor element (103) is sealed by the second

sealing resin agent (162).

15. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 12 to 14, wherein the second sealing resin agent (162) is a film-shaped.
16. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 12 to 14, wherein the second sealing resin agent (162) is in liquid state.
17. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 16 further comprising:
providing a conductive adhesive (106) to the projecting electrode (104) on the semiconductor element (103) while disposing the insulating adhesive (107) at least at either of the opposite faces of the circuit board (101) and semiconductor element (103);
setting the conductive adhesive (106) parallel with the setting of the insulating adhesive (107) in a parallel setting process, so that the electrode (102) on the circuit board (101) is further electrically connected with the projecting electrode (104) on the semiconductor element (103).
18. The method for mounting a semiconductor element (103) to a circuit board (101) according to claim 17,
wherein, in order to surely bond the electrode (102) on the circuit board (101) with the projecting electrode (104) on the semiconductor element (103), in the parallel setting process of the conductive adhesive (106) and the insulating adhesive (107), the insulating adhesive (107) is set and shrunken before the conductive adhesive (106) is set.
19. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 18,
wherein in the setting of the insulating adhesive (107), in order to prevent the semiconductor element (103) and circuit board (101) from being damaged by the setting and shrink of the insulating adhesive (107), a setting stress acting to the semiconductor element (103) and circuit board (101) by the setting and shrink of the insulating adhesive (107) is designed to be 392.3×10^5 - 1176.8×10^5 Pa.

20. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 19, wherein the projecting electrode (104) is formed of Au, Ni, Al, Cu or solder.
21. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 20, wherein the insulating adhesive (107) is thermoset.
22. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 1 to 21, wherein the insulating adhesive (107) is an epoxy-series resin, a silicone-series resin or a polyimide-series resin.
23. The method for mounting a semiconductor element (103) to a circuit board (101) according to any one of claims 17 to 22, wherein the conductive adhesive (106) is a conductive filler including silver or gold.
24. A semiconductor device having a semiconductor element (103) mounted to a circuit board (101) according to the mount method of any one of claims 1 to 23.